

#### HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

Low Forward Voltage: 0.75V @ +25°C

+150°C Operating Junction Temperature

High Surge Current Capacity

10A Total (5A Each Diode Leg) Guard-ring for Stress Protection

Case: TO-220-3 (2), TO-220F-3

### **Product Summary**

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F (MAX)</sub> (V) @ +25°C	I <sub>R (MAX)</sub> (mA) @ +25°C
60	2x5	0.75	0.1

# **Description**

High voltage dual Schottky rectifier suited for switch mode power supplies and other power converters. This device is intended for use in medium voltage operation, and particularly, in high frequency circuits where low switching losses and low noise are required.

MBR1060C is available in TO-220-3 (2), TO-220F-3 packages.

# **Applications**

- Power Supply Output Rectification
- Power Management
- Instrumentation

# Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

Terminals: Finish - Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)

Lead-Free Finish; RoHS Compliant (Notes 1 & 2)

Lead-Free Finish; RoHS Compliant (Notes 1 & 2)

Halogen and Antimony Free. "Green" Device (Note 3)

Available in "Green" Packages: TO-220-3 (2), TO-220F-3

Polarity: See Below

**Mechanical Data** 

Weight:

**Features** 

TO-220-3 (2)

■ TO-220-3 (2), TO-220F-3 – 1.9Grams (Approximate)



TO-220-3 (2)

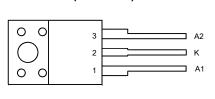


TO-220F-3

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

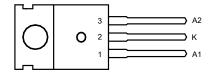
# **Pin Assignments**



(Front View)

TO-220F-3

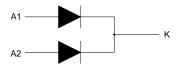
#### (Front View)



TO-220-3 (2)

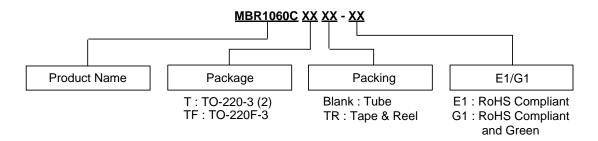


# Pin Assignments (Cont.)



Internal Structure of MBR1060C

# **Ordering Information**



Notes: 4

- 4. Not recommended for new design.
- 5. Recommended MBR1060CT-I for new design, MBR1060CT-I can replace the "MBR1060CT-G1" product.

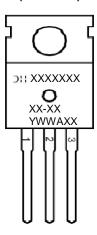
	Package	Part Number	Marking ID	Packing	
Pb)	TO-220-3 (2)	MBR1060CT-E1 (Note 4)	MBR1060CT-E1	50 Pieces/Tube	
10-220-3 (2)	MBR1060CT-G1 (Note 5)	MBR1060CT-G1	50 Pieces/Tube		
Pb	TO-220F-3	MBR1060CTF-G1 (Note 4)	MBR1060CTF-G1	50 Pieces/Tube	



# **Marking Information**

#### (1) TO-220-3 (2)

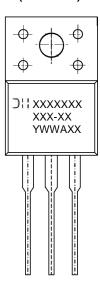
#### (Front View)



First and Second Lines: Logo and Marking ID (See Ordering Information)
Third Line: Date Code
Y: Year
WW: Work Week of Molding
A: Assembly House Code
XX: 7th and 8th Digits of Batch Number

#### (2) TO-220F-3

#### (Front View)



First and Second Lines: Logo and Marking ID (See Ordering Information)

Third Line: Date Code

Y: Year

WW: Work Week of Molding A: Assembly House Code

XX: 7th and 8th Digits of Batch Number



# Maximum Ratings (Each Diode Leg) (Note 6)

Characteristic	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V
Average Rectified Forward Current (Rated $V_R$ ) $T_C = +140$ °C	I <sub>F(AV)</sub>	5	А
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20kHz) T <sub>C</sub> = +139°C	I <sub>FRM</sub>	10	А
Non Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Half Wave, Single Phase, 60Hz)	I <sub>FSM</sub>	100	А
Operating Junction Temperature (Note 7)	TJ	+150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt	10000	V/µs
ESD (Machine Model = C)	_	> 400	V
ESD (Human Body Model = 3B)	_	> 8000	V

Notes:

### **Thermal Characteristics**

Characteristic	Symbol	Rat	Unit	
Maximum Thermal Resistance (Junction to Case)	R <sub>θJC</sub>	TO-220-3 (2)	3.0	°C/W
(Note 8)		TO-220F-3	3.5	
Maximum Thermal Resistance (Junction to Ambient) (Note 8)	R <sub>θJA</sub>	TO-220-3 (2)	60	
		TO-220F-3	50	

# Electrical Characteristics (Each Diode Leg)

Characteristic	Symbol	Rating	Unit	Test Condition
Maximum Instantaneous Forward Voltage Drop (Note 9)	V <sub>F</sub>	0.75	V	I <sub>F</sub> = 5A, T <sub>C</sub> = +25°C
		0.65		I <sub>F</sub> = 5A, T <sub>C</sub> = +125°C
		0.90		I <sub>F</sub> = 10A, T <sub>C</sub> = +25°C
		0.80		I <sub>F</sub> = 10A, T <sub>C</sub> = +125°C
	I <sub>R</sub>	0.1	mA	Rated DC Voltage, T <sub>C</sub> = +25°C
Maximum Instantaneous Reverse Current (Note 9)		15.0		Rated DC Voltage, T <sub>C</sub> = +125°C

Notes:

- 8. Device mounted on heat sink, with minimum recommended pad layout per http://www.diodes.com/package-outlines.html.
- 9. Short duration pulse test used to minimize self-heating effect, Pulse Test: Pulse Width = 300µs, Duty Cycle ≤ 2.0%.

<sup>6.</sup> Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

<sup>7.</sup> The heat generated must be less than the thermal conductivity from Junction to Ambient:  $dP_D/dT_J < 1/\theta_{JA}$ .



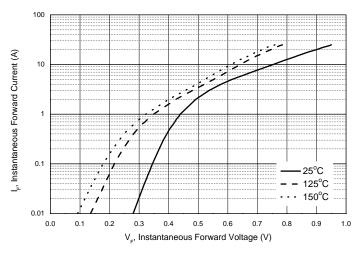


Figure 1. Typical Forward Voltage Per Diode

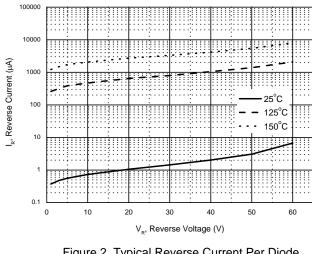


Figure 2. Typical Reverse Current Per Diode

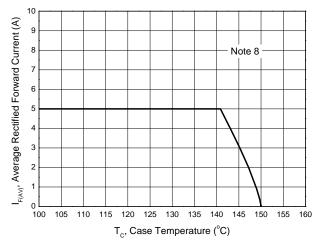
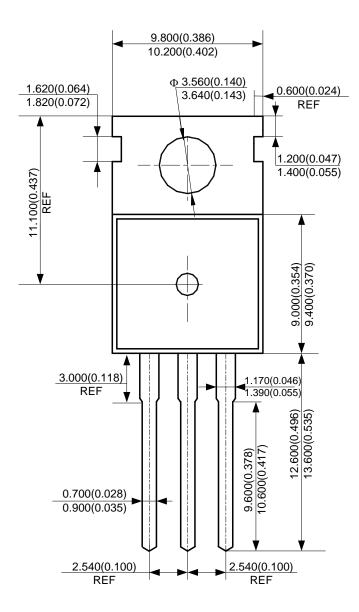


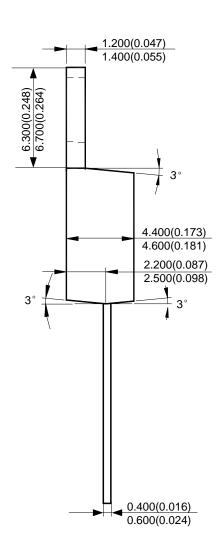
Figure 3. Average Rectified Forward Current vs. Case Temperature (Per Diode)



### Package Outline Dimensions (All dimensions in mm(inch).)

### (1) Package Type: TO-220-3 (2)

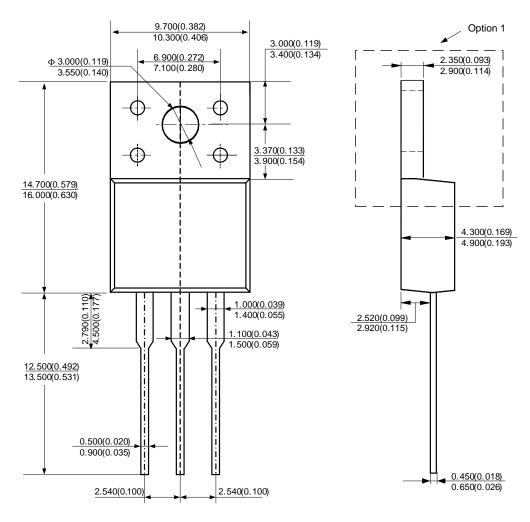






# Package Outline Dimensions (Cont. All dimensions in mm(inch).)

### (2) Package Type: TO-220F-3



Option 2

3.190(0.126)
3.250(0.128)
5°
5°



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